



PATENT  
97-CCP-251 DIV

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
ERIC GERRITSEN, et al. )  
Serial No.: 09/858,400 )  
Filed: May 16, 2001 )  
For: PROCESS FOR FORMING A )  
LOW-RESISTIVITY TITANIUM )  
SILICIDE LAYER ON A SILICON )  
SEMICONDUCTOR SUBSTRATE )  
AND THE RESULTING DEVICE )

Group Art Unit: 2813

Examiner: T. Nguyen

#3/Election  
AND  
10/24/02

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ELECTION

Commissioner for Patents  
Washington, D.C. 20231

Sir:

In response to the Office Action dated September 23, 2002, in connection with the above-identified application, please enter and consider the following remarks.

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Stephen Bongini  
Applicant, Assignee, or Representative

[Signature] 10/15/02  
Signature Dated